N-Channel IGBT 600V, 12A, VCE(sat);1.4V TO-3PF-3L

Features

- V_{CE}(sat)=1.4V typ. (I_C=12A, V_{GE}=15V)
- Low switching loss in higher frequency applications
- Enhansment type
- 5µs short circuit capability
- Adoption of full isolation type package

Applications

- Power factor correction of white goods appliance
- General purpose inverter

Specifications

Absolute Maximum Ratings at Ta = 25°C, Unless otherwise specified

Parameter	Symbol	Conditions		Ratings	Unit		
Collector to Emitter Voltage	VCES					600	V
Gate to Emitter Voltage	VGES		±20	V			
Collector Current (DC)	1	Limited by Tjmax	@ Tc=25°C * ²	24	А		
	IC*1		@ Tc=100°C *2	12	А		
Collector Current (Pulse)	ICP	Pulse width Limited by	88	А			
Allowable Power Dissipation	PD	Tc=25°C (Our ideal heat dissipation condition) *2		54	W		
Junction Temperature	Tj			150	°C		
Storage Temperature	Tstg			- 55 to +150	°C		

Note : *1 Collector Current is calculated from the following formula.

 $I_{C}(Tc) = \frac{I_{J}(Tc) + Tc}{R_{th}(j-c) \times V_{CE}(sat)(Tc)}$

 $*^2$ Our condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Electrical Characteristics at Ta = 25°C, Unless otherwise specified

D	0	Conditions		Ratings			11.2
Parameter	Symbol			min	typ	max	Unit
Collector to Emitter Breakdown Voltage	V(BR)CES	IC=500μA, VGE=0V		600			V
Collector to Emitter Cut off Current	ICES	V _{CE} =600V, V _{GE} =0V	Tc=25°C			10	μΑ
			Tc=125°C			1	mA
Gate to Emitter Leakage Current	IGES	$V_{GE}=\pm 20V$, $V_{CE}=0V$				±100	nA
Gate to Emitter Threshold Voltage	VGE(th)	V _{CE} =20V, I _C =250µA		4.5		6.5	V
Collector to Emitter Seturation Voltage			Tc=25°C		1.4	1.6	V
Collector to Emitter Saturation Voltage	V _{CE} (sat)	VGE=15V, IC=12A	Tc=125°C		1.6		V
Input Capacitance	Cies				2000		pF
Output Capacitance	Coes	V _{CE} =20V,f=1MHz			60		pF
Reverse Transfer Capacitance	Cres				50		pF

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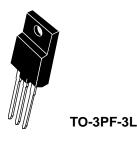
ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.



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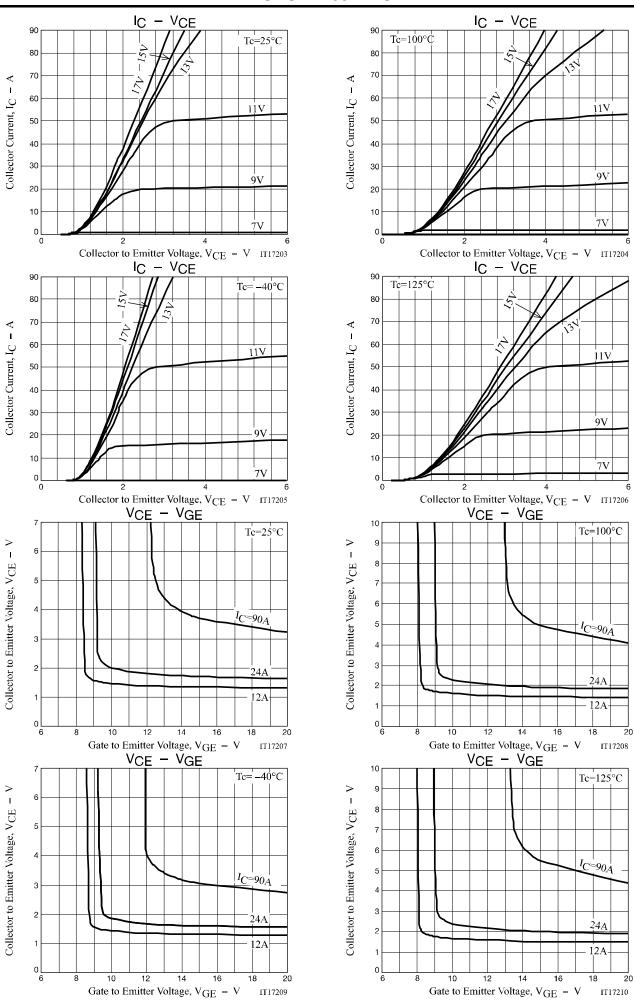


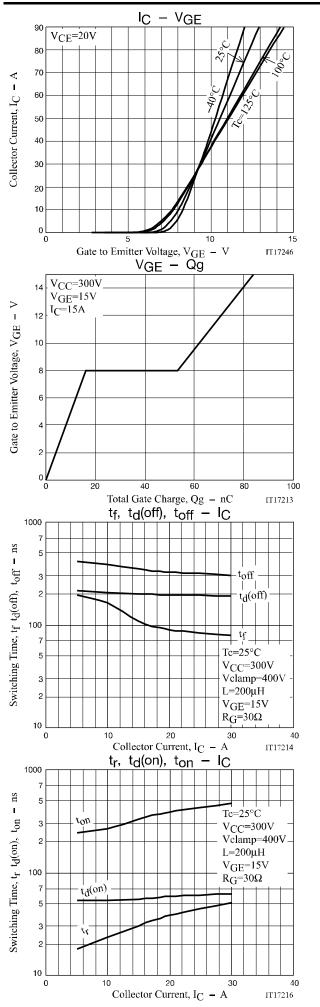
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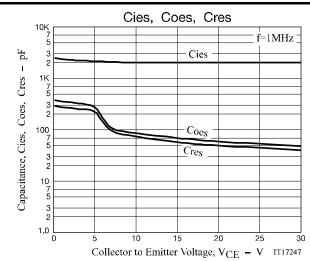
D			Ratings			
Parameter	Symbol	Conditions	min	typ	max	Unit
Turn-ON Delay Time	t _d (on)	V _{CC} =300V,I _C =15A 55 V _{CC} =30Ω,L=200µH 30 V _{GE} =0V/15V 200 Vclamp=400V 110 See Fig.1, See Fig.2 350		55		ns
Rise Time	tr			30		ns
Turn-ON Time	ton			ns		
Turn-OFF Delay Time	t _d (off)			ns		
Fall Time	tf			ns		
Turn-OFF Time	toff			350		ns
Total Gate Charge	Qg			84		nC
Gate to Emitter Charge	Qge	V _{CE} =300V, V _{GE} =15V, I _C =15A		16		nC
Gate to Collector "Miller" Charge	Qgc			37		nC

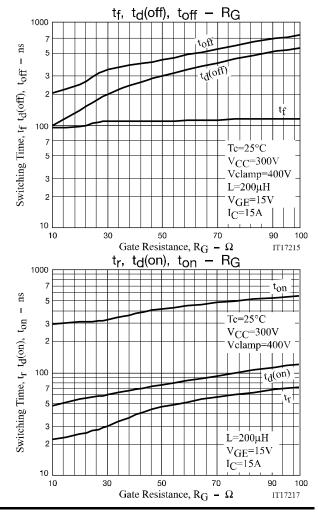
Thermal Characteristics at Ta = 25°C, Unless otherwise specified

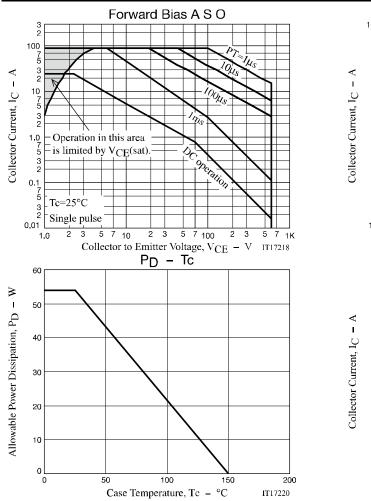
Parameter	Symbol	Conditions	Ratings	Unit
Thermal Resistance (junction- Case)	Rth(j-c)	Tc=25°C (our ideal heat dissipation condition)*2	2.33	°C /W
Thermal Resistance (junction- atmosphere)	Rth(j-a)		47.5	°C /W

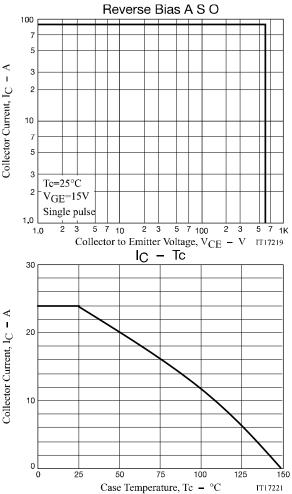












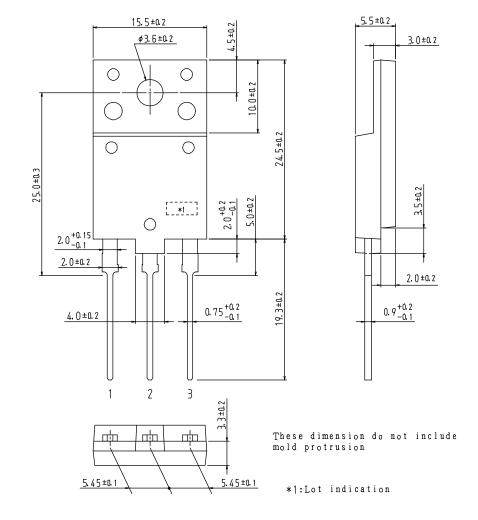
Package Dimensions

NGTG12N60TF1G

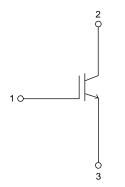
TO-3PF-3L

CASE 340AH ISSUE O

- Unit : mm
- 1: Gate
- 2: Collector
- 3: Emitter



Electrical Connection



Ordering & Package Information

-		U		
	Device	Package	Shipping	note
	NGTG12N60TF1G	TO-3PF-3L SC-94	30 pcs. / tube	Pb-Free

Marking

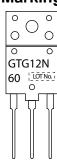


Fig.1 Switching Time Test Circuit

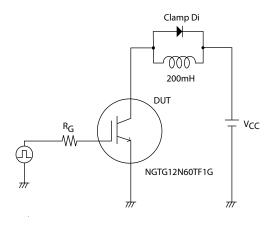
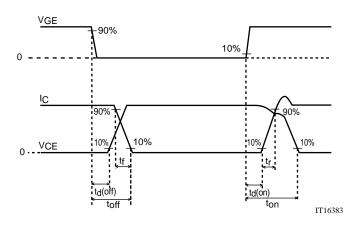


Fig.2 Timing Chart



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